

### **Bi-directional ESD Protection Diode**

#### **FEATURES**

- Meet IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- Designed for mounting on small surface
- Protects one Bi-directional I/O line
- Moisture sensitivity level 1
- Working Voltage : 5V, 12V, 24V
- Pb free version and RoHS compliant
- Packing code with suffix "G" means green compound (halogen-free)









#### **MECHANICAL DATA**

- Case: 1005 small outline plastic package
- Terminal : Gold plated, solder per MIL-STD-705, method 2026 guaranteed
- High temperature soldering guaranteed : 260°C/10s
- Weight: 6 ± 0.5 mg

#### **APPLICATIONS**

- Cell Phone Handsets and Accessories
- Notebooks, Desktops, and Servers
- Keypads, Side Keys, USB 2.0, LCD Displays
- Portable Instrumentation
- Touch Panel

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)					
PARAMETER		SYMBOL	VALUE	UNIT	
D 1 D 1 D	TESDL5V0		75		
Peak Pulse Power (tp=8/20µs waveform)	TESDL12V	P <sub>PP</sub>	25	W	
(τρ-0/20μ3 wavelolli)	TESDL24V		47		
ESD per IEC 61000-4-2 (Air)		V <sub>ESD</sub>	± 15	KV	
ESD per IEC 61000-4-2 (Contact)		V ESD	± 8		
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

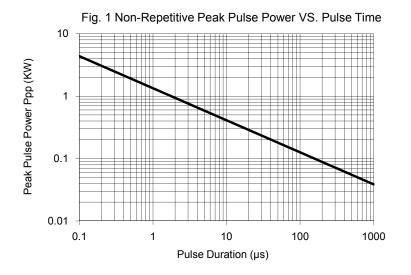
PAI	RAMETER		SYMBOL	MIN	MAX	UNIT
	TESDL5V0			-	5	
Reverse Stand-Off Voltage	TESDL12V		$V_{RWM}$	-	12	V
	TESDL24V			-	24	
	TESDL5V0			5.1	-	
Reverse Breakdown Voltage	TESDL12V	I <sub>R</sub> = 1 mA	$V_{(BR)}$	13	-	V
	TESDL24V			25	-	
	TESDL5V0	$V_R = 5 V$				
Reverse Leakage Current	TESDL12V	$V_R = 12 V$	I <sub>R</sub>	- 2	2	μA
	TESDL24V	$V_R = 24 V$				
Clamping Voltage	TESDL5V0	I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	9.8	V
Clamping Voltage	I E S D L S V U	$I_{PP} = 5 A$	V <sub>C</sub>	-	15	V
Clamping Voltage	TESDL12V	I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	25	V
Clamping Voltage	TESDLIZV	$I_{PP} = 5 A$	V <sub>C</sub>	-	33	V
Clamping Voltage	TECDI 24V	I <sub>PP</sub> = 1 A	V	-	47	V
	TESDL24V $I_{PP} = 5 A$	$I_{PP} = 5 A$	V <sub>C</sub>	-	51	V
Junction Capacitance	TESDL5V0			15		
	TESDL12V	$V_R = 0 V$ f = 1.0 MHz	CJ		12	pF
	TESDL24V	T = 1.0 IVIHZ			10	

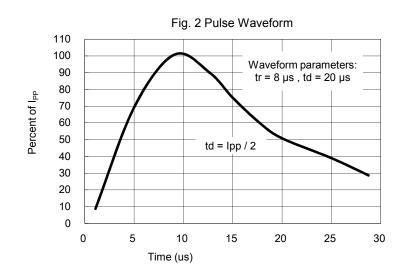


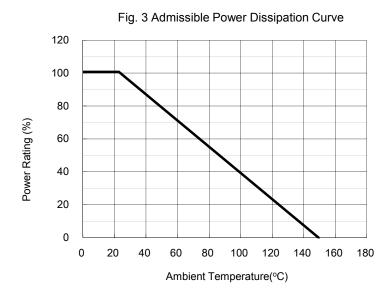


#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub>=25°C unless otherwise noted)







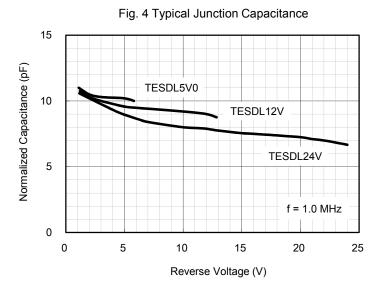
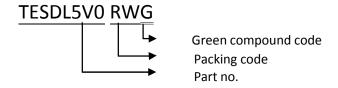


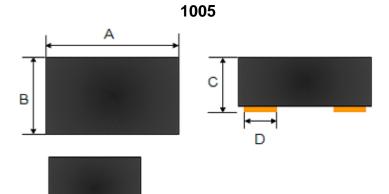
Fig. 5 Clamping Voltage VS. Peak Pulse Current 60 50 TESDL24V Clamping Voltage (V) 40 30 TESDL12V 20 10 Waveform parameters: TESDL5V0  $tr = 8 \mu s$ ,  $td = 20 \mu s$ 0 0 1 Peak Pulse Current (A)



# **ORDER INFORMATION (EXAMPLE)**

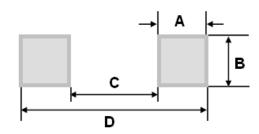


### PACKAGE OUTLINE DIMENSIONS



DIM.	Unit (mm)		Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	2.40	2.60	0.094	0.102	
В	1.10	1.30	0.043	0.051	
С	0.70	0.90	0.028	0.035	
D	0.50 (Typ.)		0.020 (Typ.)		
Е	1.00 (Typ.)		0.040	(Тур.)	

### **SUGGEST PAD LAYOUT**



DIM.	Unit (mm)	Unit (inch)	
Dilvi.	Тур.	Тур.	
Α	0.70	0.028	
В	1.30	0.051	
С	1.30	0.051	
D	2.70	0.106	

Note: The suggested land pattern dimensions have been provided for reference only, as actual pad layouts may vary depending on application.

### **MARKING**

Part No.	Marking
TESDL5V0	E05
TESDL12V	E12
TESDL24V	E24

Document Number: DS\_S1501022



Taiwan Semiconductor

#### **APPLICATION INFROMATION**

- Designed to protect one data, I/O, or power supply line
- Designed to protect sensitive electronics from damage or latch-up due to ESD
- Designed to replace multilayer varistors (MLVs) in portable applications
- Features large cross-sectional area junctions for conducting high transient currents
- Offers superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs
- The combination of small size and high ESD surge capability makes them ideal for use in portable applications

#### **CIRCUIT BOARD LAYOUT RECOMMENDATIONS**

- Good circuit board layout is critical for the suppression of ESD induced transients
- Place the ESD Protection Diode near the input terminals or connectors to restrict transient coupling
- Minimize the path length between the ESD Protection Diode and the protected line
- Minimize all conductive loops including power and ground loops
- The ESD transient return path to ground should be kept as short as possible
- Never run critical signals near board edges
- Use ground planes whenever possible

Document Number: DS\_S1501022 Version: E15

Taiwan Semiconductor



**Small Signal Product** 

## Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied,to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or seling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Document Number: DS\_S1501022 Version: E15

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

### Taiwan Semiconductor:

TESDL12V TESDL24V TESDL5V0 TESDL24V RWG TESDL5V0 RWG TESDL12V RWG